SUP60061EL

Vishay Siliconix

www.vishay.com

P-Channel 80 V (D-S) MOSFET



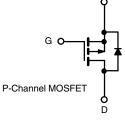
PRODUCT SUMMARY					
V _{DS} (V)	-80				
$R_{DS(on)}$ max. (Ω) at V_{GS} = -10 V	0.0058				
$R_{DS(on)}$ max. (Ω) at V_{GS} = -4.5 V	0.0081				
Q _g typ. (nC)	145				
I _D (A)	-150				
Configuration	Single				

FEATURES

- TrenchFET[®] power MOSFET
- · Package with low thermal resistance
- Maximum 175 °C junction temperature
- Low R_{DS(on)} minimizes power loss from conduction
- · Compatible with logic-level gate driving
- 100 % R_q and UIS tested
- Material categorization: for definitions of compliance please see <u>www.vishay.com/doc?99912</u>

APPLICATIONS

- · Battery protection
- Motor drive control
- Load switch



S

ORDERING INFORMATION	
Package	TO-220AB
Lead (Pb)-free and halogen-free	SUP60061EL-GE3

ABSOLUTE MAXIMUM RATINGS ($T_c = 25$ °	°C, unless otherw	ise noted)			
PARAMETER		SYMBOL	LIMIT	UNIT	
Drain-source voltage		V _{DS}	-80	v	
Gate-source voltage		V _{GS}	± 20	v	
Continuous drain current ^d	T _C = 25 °C		-150 ^d		
$(T_{\rm J} = 175 \ ^{\circ}{\rm C})$	T _C = 70 °C	I _D	-150 ^d	<u>^</u>	
Pulsed drain current (100 μs)		I _{DM}	-250	A	
Avalanche current			-75		
Single pulse avalanche energy ^a	L = 0.1 mH	E _{AS}	281	mJ	
Dower discipation	T _C = 25 °C °	D	375	w	
Power dissipation	T _C = 125 °C ^b	P _D	125	vv	
Operating junction and storage temperature range		T _J , T _{stg}	-55 to +175	°C	

THERMAL RESISTANCE RATINGS				
PARAMETER		SYMBOL	LIMIT	UNIT
Junction-to-ambient	PCB mount ^b	R _{thJA}	40	°C/W
Junction-to-case		R _{thJC}	0.4	0/10

Notes

- a. Duty cycle ≤ 1 %
- b. When mounted on 1" square PCB (FR4 material)
- c. See SOA curve for voltage derating
- d. Limited by package

S21-0031-Rev. A, 25-Jan-2021

1



COMPLIANT HALOGEN

SUP60061EL

SPECIFICATIONS ($T_J = 25$ °C	C, unless ot	herwise noted)				
PARAMETER	SYMBOL	TEST CONDITIONS	MIN.	TYP.	MAX.	UNIT
Static						
Drain-source breakdown voltage	V _{DS}	$V_{GS} = 0 V, I_D = -10 mA$	-80	-	-	V
Gate threshold voltage	V _{GS(th)}	$V_{DS} = V_{GS}$, $I_D = -250 \ \mu A$	-1.5	-	-2.5	v
Gate-body leakage	I _{GSS}	$V_{DS} = 0 V, V_{GS} = \pm 20 V$	-	-	± 100	nA
		$V_{DS} = -80 V, V_{GS} = 0 V$	-	-	-1	
Zero gate voltage drain current	I _{DSS}	V_{DS} = -80 V, V_{GS} = 0 V, T_{J} = 125 °C	-	-	-50	μA
		V_{DS} = -80 V, V_{GS} = 0 V, T_{J} = 175 °C	-	-	-250	
On-state drain current ^a	I _{D(on)}	$V_{DS} \le -5 \text{ V}, \text{ V}_{GS} = -10 \text{ V}$	-30	-	-	А
Drain-source on-state resistance ^a	P	V _{GS} = -10 V, I _D = -20 A	-	0.0048	0.0058	0
Drain-source on-state resistance "	R _{DS(on)}	$V_{GS} = -4.5 \text{ V}, \text{ I}_{D} = -15 \text{ A}$	-	0.0065	0.0081	Ω
Forward transconductance ^a	g fs	$V_{DS} = -15 \text{ V}, \text{ I}_{D} = -15 \text{ A}$	-	80	-	S
Dynamic ^b						
Input capacitance	Ciss		-	9600	-	
Output capacitance	$\begin{tabular}{ c c c c c }\hline $C_{iss} & C_{oss} \\ \hline C_{oss} \\ \hline C_{rss} \\ \hline $V_{GS} = 0 $ V, $V_{DS} = -40 $ V, $f = 1 $ MHz$ \\ \hline $-$ 3300 \\ \hline $-$ 110 \\ \hline $-$ 110 \\ \hline $-$ 10 \\ \hline $-$ $$	-	pF			
Reverse transfer capacitance	C _{rss}		-	110	-	
Total gate charge ^c	Qg		-	145	218	
Gate-source charge ^c	Q _{gs}	V _{DS} = -40 V, V _{GS} = -10 V, I _D = -110 A		34	-	nC
Gate-drain charge ^c	Q _{gd}		-	16	-	l
Gate resistance	Rg	f = 1 MHz	0.46	2.3	4.6	Ω
Turn-on delay time ^c	t _{d(on)}		-	25	35	
Rise time ^c	t _r	V_{DD} = -40 V, R_L = 0.71 Ω	-	20	30	
Turn-off delay time ^c	t _{d(off)}	$I_D \cong$ -20 A, V_{GEN} = -10 V, R_g = 1 Ω	-	90	140	ns
Fall time ^c	t _f		-	20	30	
Drain-Source Body Diode Characte	ristics (T _C = 25	⁵ °C ^b)				
Continuous current	I _S		-	-	-150	A
Pulsed current	I _{SM}		-	-	-250	A
Forward voltage ^a	V _{SD}	$I_{\rm F}$ = -10 A, $V_{\rm GS}$ = 0 V	-	-0.8	-1.5	V
Reverse recovery time	t _{rr}		-	90	135	ns
Peak reverse recovery charge	I _{RM(REC)}	I _F = -20 A, dl/dt = 100 A/μs	-	-2.8	-4.2	А
Reverse recovery charge	Q _{rr}		-	145	218	nC

Notes

a. Pulse test; pulse width \leq 300 µs, duty cycle \leq 2 %

b. Guaranteed by design, not subject to production testing

www.vishay.com

c. Independent of operating temperature

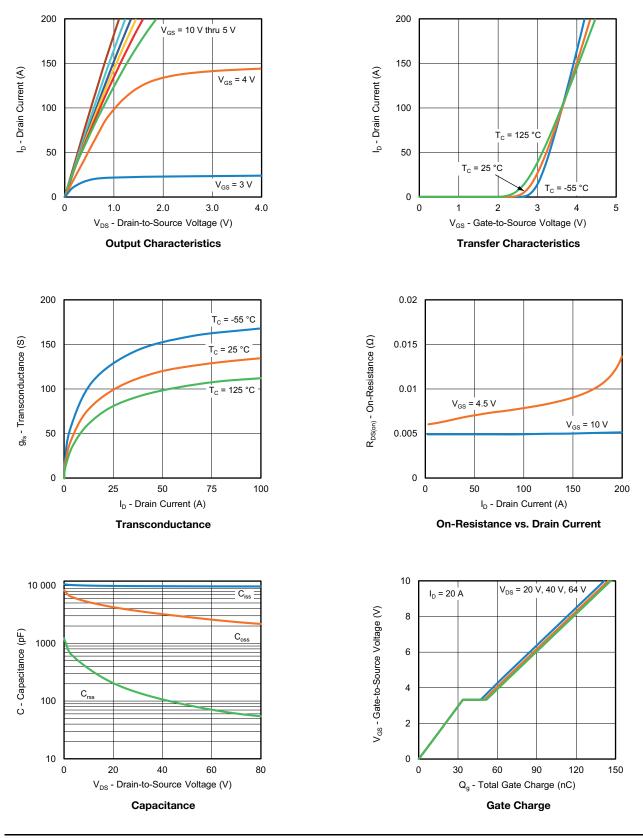
Stresses beyond those listed under "Absolute Maximum Ratings" may cause permanent damage to the device. These are stress ratings only, and functional operation of the device at these or any other conditions beyond those indicated in the operational sections of the specifications is not implied. Exposure to absolute maximum rating conditions for extended periods may affect device reliability.



SUP60061EL

Vishay Siliconix

TYPICAL CHARACTERISTICS (T_A = 25 °C, unless otherwise noted)



S21-0031-Rev. A, 25-Jan-2021

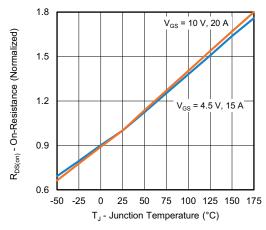
3

Document Number: 63020

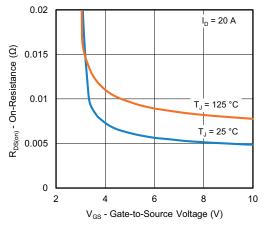
For technical questions, contact: <u>pmostechsupport@vishay.com</u> THIS DOCUMENT IS SUBJECT TO CHANGE WITHOUT NOTICE. THE PRODUCTS DESCRIBED HEREIN AND THIS DOCUMENT ARE SUBJECT TO SPECIFIC DISCLAIMERS, SET FORTH AT <u>www.vishay.com/doc?91000</u>



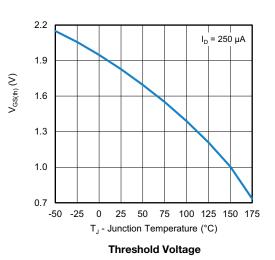
TYPICAL CHARACTERISTICS ($T_A = 25 \text{ °C}$, unless otherwise noted)

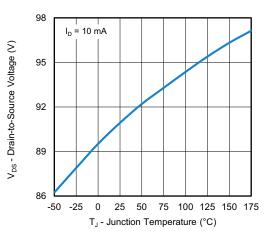


On-Resistance vs. Junction Temperature

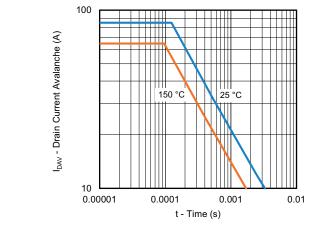


On-Resistance vs. Gate-to-Source Voltage





Drain Source Breakdown vs. Junction Temperature



Avalanche Current vs. Time

T = 25 °C

T₁ = 150 °C

0.01 0 0.2 0.4 0.6 0.8 1.0 1.2 V_{SD} - Source-to-Drain Voltage (V)

Source Drain Diode Forward Voltage

S21-0031-Rev. A, 25-Jan-2021

100

10

0.1

Is - Source Current (A)

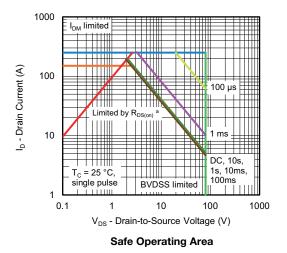
4

Document Number: 63020

For technical questions, contact: <u>pmostechsupport@vishay.com</u> THIS DOCUMENT IS SUBJECT TO CHANGE WITHOUT NOTICE. THE PRODUCTS DESCRIBED HEREIN AND THIS DOCUMENT ARE SUBJECT TO SPECIFIC DISCLAIMERS, SET FORTH AT <u>www.vishay.com/doc?91000</u>

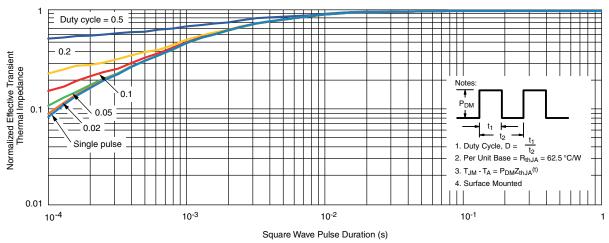


THERMAL RATINGS ($T_A = 25 \text{ °C}$, unless otherwise noted)



Note

a. V_{GS} > minimum V_{GS} at which $R_{DS(on)}$ is specified



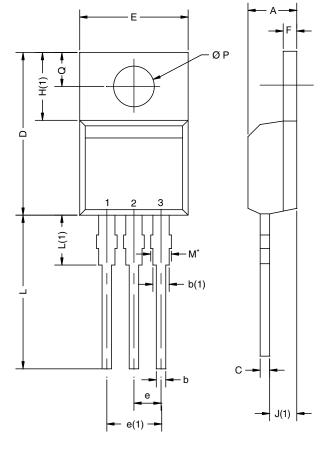
Normalized Thermal Transient Impedance, Junction-to-Case

Vishay Siliconix maintains worldwide manufacturing capability. Products may be manufactured at one of several qualified locations. Reliability data for Silicon Technology and Package Reliability represent a composite of all qualified locations. For related documents such as package / tape drawings, part marking, and reliability data, see <u>www.vishay.com/ppg?63020</u>.

S21-0031-Rev. A, 25-Jan-2021	5	Document Number: 63020
Fo	r technical questions, contact: pmostechsupport@vishay.	com
THIS DOCUMENT IS SUBJECT TO	CHANGE WITHOUT NOTICE. THE PRODUCTS DESCRIE	BED HEREIN AND THIS DOCUMENT
ARE SUBJECT	TO SPECIFIC DISCLAIMERS, SET FORTH AT www.vishav	<u>com/doc?91000</u>



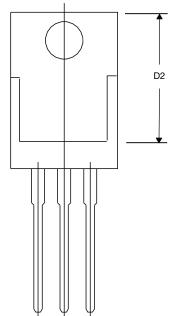
TO-220AB



	MILLIMETERS		RS INCHES	
DIM.	MIN.	MAX.	MIN.	MAX.
А	4.25	4.65	0.167	0.183
b	0.69	1.01	0.027	0.040
b(1)	1.20	1.73	0.047	0.068
С	0.36	0.61	0.014	0.024
D	14.85	15.49	0.585	0.610
D2	12.19	12.70	0.480	0.500
Е	10.04	10.51	0.395	0.414
е	2.41	2.67	0.095	0.105
e(1)	4.88	5.28	0.192	0.208
F	1.14	1.40	0.045	0.055
H(1)	6.09	6.48	0.240	0.255
J(1)	2.41	2.92	0.095	0.115
L	13.35	14.02	0.526	0.552
L(1)	3.32	3.82	0.131	0.150
ØΡ	3.54	3.94	0.139	0.155
Q	2.60	3.00	0.102	0.118
ECN: T14- DWG: 547	0413-Rev. P, 1	16-Jun-14		

Note

 * M = 1.32 mm to 1.62 mm (dimension including protrusion) Heatsink hole for HVM



Revison: 16-Jun-14

THIS DOCUMENT IS SUBJECT TO CHANGE WITHOUT NOTICE. THE PRODUCTS DESCRIBED HEREIN AND THIS DOCUMENT ARE SUBJECT TO SPECIFIC DISCLAIMERS, SET FORTH AT www.vishay.com/doc?91000



Vishay

Disclaimer

ALL PRODUCT, PRODUCT SPECIFICATIONS AND DATA ARE SUBJECT TO CHANGE WITHOUT NOTICE TO IMPROVE RELIABILITY, FUNCTION OR DESIGN OR OTHERWISE.

Vishay Intertechnology, Inc., its affiliates, agents, and employees, and all persons acting on its or their behalf (collectively, "Vishay"), disclaim any and all liability for any errors, inaccuracies or incompleteness contained in any datasheet or in any other disclosure relating to any product.

Vishay makes no warranty, representation or guarantee regarding the suitability of the products for any particular purpose or the continuing production of any product. To the maximum extent permitted by applicable law, Vishay disclaims (i) any and all liability arising out of the application or use of any product, (ii) any and all liability, including without limitation special, consequential or incidental damages, and (iii) any and all implied warranties, including warranties of fitness for particular purpose, non-infringement and merchantability.

Statements regarding the suitability of products for certain types of applications are based on Vishay's knowledge of typical requirements that are often placed on Vishay products in generic applications. Such statements are not binding statements about the suitability of products for a particular application. It is the customer's responsibility to validate that a particular product with the properties described in the product specification is suitable for use in a particular application. Parameters provided in datasheets and / or specifications may vary in different applications and performance may vary over time. All operating parameters, including typical parameters, must be validated for each customer application by the customer's technical experts. Product specifications do not expand or otherwise modify Vishay's terms and conditions of purchase, including but not limited to the warranty expressed therein.

Hyperlinks included in this datasheet may direct users to third-party websites. These links are provided as a convenience and for informational purposes only. Inclusion of these hyperlinks does not constitute an endorsement or an approval by Vishay of any of the products, services or opinions of the corporation, organization or individual associated with the third-party website. Vishay disclaims any and all liability and bears no responsibility for the accuracy, legality or content of the third-party website or for that of subsequent links.

Except as expressly indicated in writing, Vishay products are not designed for use in medical, life-saving, or life-sustaining applications or for any other application in which the failure of the Vishay product could result in personal injury or death. Customers using or selling Vishay products not expressly indicated for use in such applications do so at their own risk. Please contact authorized Vishay personnel to obtain written terms and conditions regarding products designed for such applications.

No license, express or implied, by estoppel or otherwise, to any intellectual property rights is granted by this document or by any conduct of Vishay. Product names and markings noted herein may be trademarks of their respective owners.